Supporting information for

Multiformity and fluctuation of Cu ordering in Cu₂Se thermoelectric materials

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The detailed information of S3 structure predicted by the first-principle calculation is list in Table S1.

Table S1. Lattice parameters of the predicted S3 structure (space group: P1) with a=7.545Å,

Atom	x/a	y/b	z/c	Atom	x/a	y/b	z/c
Cu1	0.65872	0.16449	0.54796	Cu19	0.31222	0.98502	0.94233
Cu2	0.68551	0.48925	0.56271	Cu20	0.32016	0.32877	0.93937
Cu3	0.74949	0.82805	0.58204	Cu21	0.18823	0.65965	0.89654
Cu4	0.44097	0.14872	0.17336	Cu22	0.55579	0.96902	0.3474
Cu5	0.43053	0.53431	0.12898	Cu23	0.56427	0.34267	0.2819
Cu6	0.42916	0.79832	0.11399	Cu24	0.54841	0.67065	0.41159
Cu7	0.6878	0.01493	0.05711	Se25	0.23425	0.15781	0.75488
Cu8	0.81196	0.34026	0.103	Se26	0.22717	0.4928	0.7405
Cu9	0.67972	0.67116	0.06024	Se27	0.21603	0.82655	0.7325
Cu10	0.44426	0.03092	0.65213	Se28	0.22307	0.0022	0.24493
Cu11	0.45155	0.32949	0.58806	Se29	0.22036	0.34161	0.24348
Cu12	0.43576	0.65726	0.71762	Se30	0.2116	0.67318	0.24038
Cu13	0.2508	0.17202	0.41755	Se31	0.78395	0.17341	0.26705
Cu14	0.31423	0.51083	0.43682	Se32	0.77281	0.50712	0.25903

b=12.416 Å, *c*=7.110 Å, *α*=90.030°, *β*=108.395°, and *γ*=90.342°.

Cu15	0.34115	0.8356	0.4516	Se33	0.76575	0.84215	0.2446
Cu16	0.57077	0.20171	0.88553	Se34	0.777	0.99786	0.75458
Cu17	0.56946	0.46568	0.87096	Se35	0.78836	0.32688	0.75909
Cu18	0.55912	0.85119	0.8261	Se36	0.77959	0.65846	0.75607

Table S2. Energies of different structures calculated by the first-principles method. The energy of the cubic β -phase (S0) is set as reference and energies are rescaled for one Cu₂Se

	formula unit.	
Structure Label	Space Group	E(eV)
S0	$Fm\overline{3}m$ (225)	0
S1	$P\overline{1}$ (2)	-0.2921
S2	C2/c (15)	-0.2920
S3	P1 (2)	-0.2990



Figure S1. A possible structure for the four-fold periodic packing sequence: (a) is the structure model consisting of four S1-type layers and a 1/6<211>_c-type displacement is involved inbetween every two layers. (b) and (c) are the simulated electron diffraction patterns according to the structural model projected along two different <112>_c directions. They match the experimental observations in Fig. 2e and Fig. 2f, respectively in the manuscript.



Figure S2. The structural models projected perpendicular to the layer plane: (a) is for S2, which shows a 3×3 super cell compared to the *fcc* cell. (b) is for S3, which shows a $3 \times 3\sqrt{3}$ super cell.



Figure S3. Domain structures in the Cu₂Se ingot: (a) is the dark-field image using the cycled reflection (i.e. 1/2{111}_c) in the diffraction pattern (b). (c) is the HREM image showing an antiphase boundary (APB) indicated by an arrow. (d) is the structure model of the APB.



Figure S4. Evolution of the electron diffraction pattern at elevating temperatures: The diffraction patterns of the powder sample at room temperature, 323K, 363K, and 393K are shown in (a), (b), (c), and (d), respectively. Extra arrays of reflections (marked by arrows) are peculiar to S3 and they disappear at 363K, a temperature before the phase transition owing to the lower energy of S3. The spots cycled in green on (c) are related to the lamellar structure, which disappear at 393K (where phase transition takes place) eventually giving a typical <110>-projected pattern of the face-centered cubic.



Figure S5: Evolution of dark-field images upon heating showing oscillation of order-disorder transition in local area. The dark-field images were acquired using circled reflections shown in the

inset.

materials.						
Compounds	Heat capacity	Sound velocity	Reference			
	(J g ⁻¹ K ⁻¹)	(m s ⁻¹)				
AgSbTe ₂	0.205	4800	33			
CoSb ₃	0.235	2934	34			
Bi ₂ Te ₃	0.156	1601	40			
PbTe	0.149	1830	41			
In ₄ Se ₃	0.251		38			
Zn_4Sb_3	0.294	2470	35			
$Ba_8Ga_{16}Ge_{30}$	0.307	3046	36			
Cu ₂ Se	0.363	2523	13			

Table S3. Room temperature heat capacity and sound velocity of some typical thermoelectric